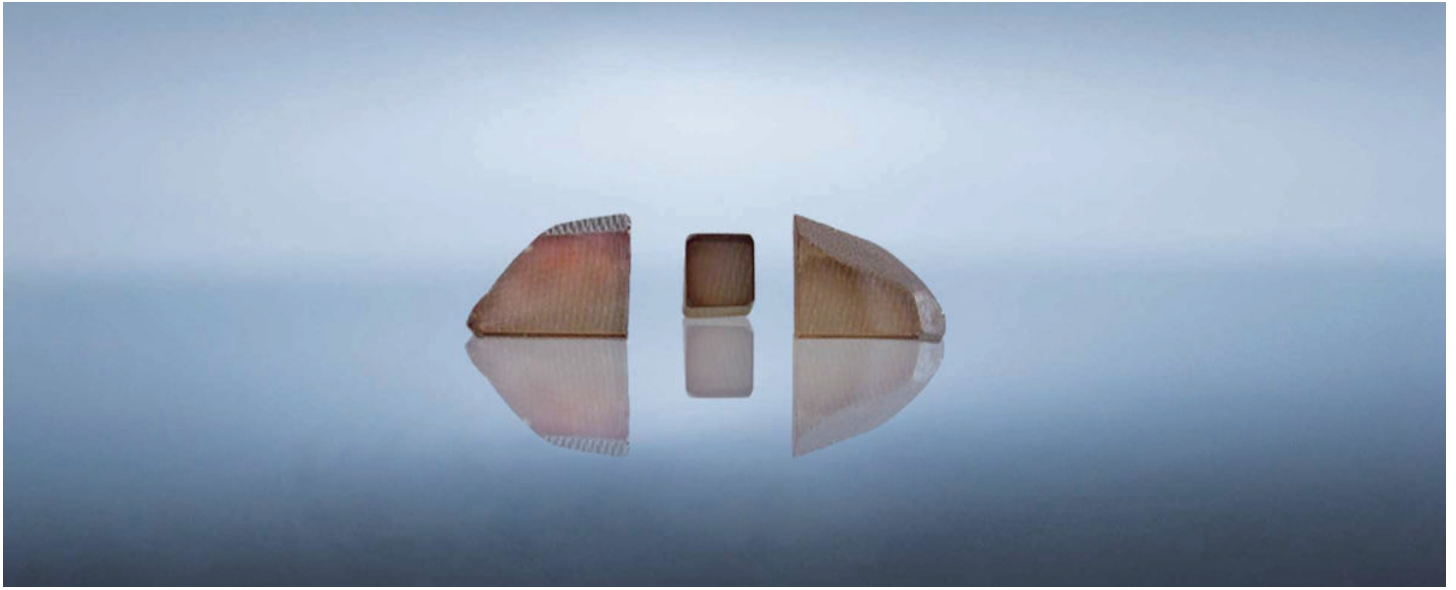


LilnSe₂



DESCRIPTION

LilnSe₂ (Lithium Indium Selenide), referred to as LISe crystal, mm² dot group, transmittance range of 0.43~13.2 μm, large effective nonlinear coefficient ($d_{31}=11.78$, $d_{24}=8.17@2.3\ \mu\text{m}$), can be applied to pump titanium sapphire laser, optical parametric oscillation (OPO) can be obtained from 1-13 μm mid-infrared laser output and mid-infrared range (2-13 μm) with different frequencies.

FEATURES

- Small band gap, suitable for neutron detection
- High heat conductivity
- High laser damage threshold
- Crystal growth is not easy to crack
- Good neutron recognition capability
- It is not easy to crack during growth

APPLICATIONS

- Optical parametric oscillation (1-13 micron OPO effective material)
- In the range of 2-13μm infrared laser difference frequency
- Through DFG OPA OPO and other ways to achieve long-wave infrared laser output
- Gas detection, medical diagnosis and treatment
- Infrared guidance, infrared confrontation, infrared remote sensing, etc

OPTICAL ELEMENT PARAMETERS

Positional Accuracy	<30'
Parallelism	<30"
Flatness	$\lambda/4@546\text{nm}$
Surface Finish	30/20 sratch/dig



LilnSe₂

PHYSICAL AND CHEMICAL PROPERTIES

Crystal Structure	Orthorhombic, point group: mm2, space groups: Pna2 ₁
Lattice Parameters Å	a=7.192, b=8.412, c=6.793
Transparency Range	0.43-13µm
Nonlinear Coefficient pm/V	d ₃₁ =11.78, d ₂₄ =8.17 @2.3µm
Standard Reflectance	@10.0 µm n _x =2.2015, n _y =2.2522, n _z =2.2566 @5.0 µm n _x =2.2370, n _y =2.2772, n _z =2.2818
SHG Fundamental Frequency Light Range	x-y, Type II, eoe: 2.73 – 8.24µm
	x-z, Type I, ooe: 2.08 – 12.4µm
	y-z, Type II, oeo: 2.73 – 3.07µm
	y-z Type II, oeo, 7.66 – 8.24µm
	Total wavelength coverage: 2.08 – 12.4µm
Damage Threshold, GW/cm ²	40 @1064nm (t=10 ns)
Thermal Conductivity, WM/M°C	k _x =4.73 ± 0.3; k _y =4.67 ± 0.3; k _z =5.45 ± 0.3
Band gap energy at room temperature	2.73eV
Far infrared absorption edge at 0.2 level of transmittance	1.24 THz @240 µm

SPECTRA

